TOSHIBA LED LAMP GaP GREEN LIGHT EMISSION

TLGD160

PANEL CIRCUIT INDICATOR

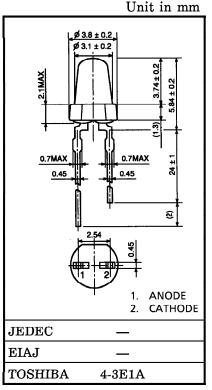
All Plastic Mold Type Clear Transparent Lens

Low Drive Current, High Intensity Green Light Emission. Recommended Forward Current: IF=15~20mA (DC)

- All Plastic Molded Lens, Provides an Excellent ON-OFF Contrast Ratio.
- Fast Response Time, Capable of Pulse Operation.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current (DC)	$_{ m IF}$	40	mA
Reverse Voltage	v_{R}	4	V
Power Dissipation	$P_{\mathbf{D}}$	120	mW
Operating Temperature Range	$T_{ m opr}$	-20~85	°C
Storage Temperature Range	$T_{ m stg}$	-30~100	°C



Weight: 0.12g

ELECTRO-OPTICAL CHARACTERISTICS (Ta = 25°C)

СНАБ	RACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward V	oltage	$ m V_{f F}$	$I_{\mathbf{F}} = 20 \text{mA}$	_	2.15	2.8	V
Reverse Cu	ırrent	$I_{ m R}$	$V_R=4V$	_	_	5	μ A
Luminous	TLGD160	I _V	I _F =20mA (Note)	140	300	-	mcd
Intensity	TLGD160 (PQ)			153	_	736	mea
Peak Emis	sion Wave Length	$\lambda_{\mathbf{p}}$	$I_F = 20 \text{mA}$	_	567	_	nm
Spectral Li	ne Half Width	Δλ	$I_F = 20 mA$		25	—	nm

(Note) Rank selection carried out under next standard range respectively, although it needs ±15% sdditionary for guaranteed limits.

> P: 180-360mcd Q:320-640mcd

Each rank products is classified by package unit, and (PQ) includes P and Q.

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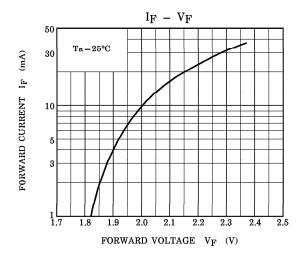
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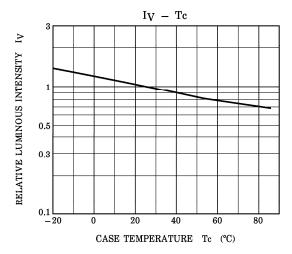
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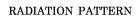
PRECAUTION

Please be careful of the followings.

- Soldering temperature: 260°C MAX. Soldering time: 3s MAX. (Soldering portion of lead: up to 2mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.







Ta = 25°C

